

STBV42D

High voltage fast-switching NPN power transistor

Preliminary data

Features

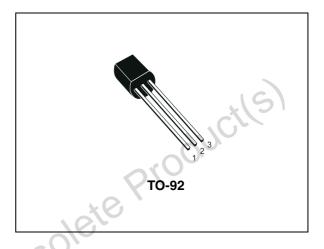
- High voltage capability
- Low spread of dynamic parameters
- Very high switching speed
- Integrated free-wheeling diode

Application

Compact fluorescent lamps (CFLs)

Description

The device is manufactured using high voltage multi epitaxial planar technology for high switching speeds and high voltage capability. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining the wide RBSOA.



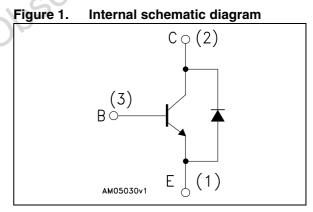


Table 1. Device summary

Order code Marking		Package	Packaging	
STBV42D	BV42D	TO-92	BAG	

April 2010

Doc ID 17236 Rev 2

www.st.com

This is preliminary information on a new product now in development or undergoing evaluation. Details are subject to change without notice.

Electrical ratings 1

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit			
V_{CES}	Collector-emitter voltage (V _{BE} = 0)	700	V			
V _{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V			
V_{EBO}	Collector-base voltage $(I_C = 0)$	9	V			
Ι _C	Collector current	1	А			
I _{CM}	Collector peak current (t _P < 5 ms)	2	Α			
Ι _Β	Base current	0.5	SA			
I _{BM}	Base peak current (t _P < 5 ms)	1 (C	Α			
P _{TOT}	Total dissipation at $T_c = 25 \text{ °C}$		W			
T _{STG}	Storage temperature	- 65 to 150	- °C			
TJ	Max. operating junction temperature 150					
Table 3. Thermal data						

Table 3. Thermal data

	Symbol Parameter		Value	Unit
	R _{thJC} Thermal resistance junction-case		125	°C/W
obsolete Producils)				



2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

Symbol	Parameter	Test o	conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current $(V_{BE} = 0)$	V _{CE} = 700 V V _{CE} = 700 V	T _C = 125 °C			1 5	mA mA
I _{EBO}	BO Emitter cut-off current $(I_{\rm C} = 0)$					1	mA
V _{CEO(sus)}	Collector-emitter sustaining voltage (I _B = 0)	I _C = 1 mA		400	~	S	V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 0.25 A I _C = 0.5 A I _C = 0.75 A	l _B = 125 mA	99	0.2 0.3 0.4	0.5 1 1.5	V V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 0.25 A I _C = 0.5 A	I _B = 50 mA I _B = 125 mA			1 1.2	V V
h _{FE} ⁽¹⁾	DC current gain	$I_{C} = 5 \text{ mA},$ $I_{C} = 0.4 \text{ A},$ $I_{C} = 0.8 \text{ A}$	V _{CE} = 2 V V _{CE} = 5 V V _{CE} = 5 V	12 10 5		30 20	
t _f	Inductive Load Fall time	$I_{C} = 0.25 \text{ A}$ $I_{B(on)} = -I_{B(off}$ L = 3 mH	V _{clamp} = 300 V) = 50 mA <i>Figure 2</i>		0.3		μs
V _F	Diode forward voltage	I _F = 350 mA				1.7	V

 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration ≤ 300 μs, duty cycle ≤ 2 %



2.1 Test circuit

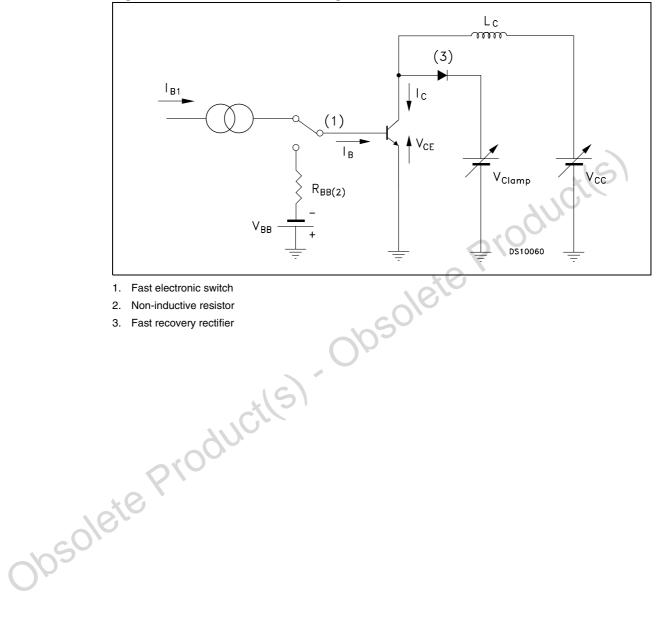


Figure 2. Inductive load switching test circuit

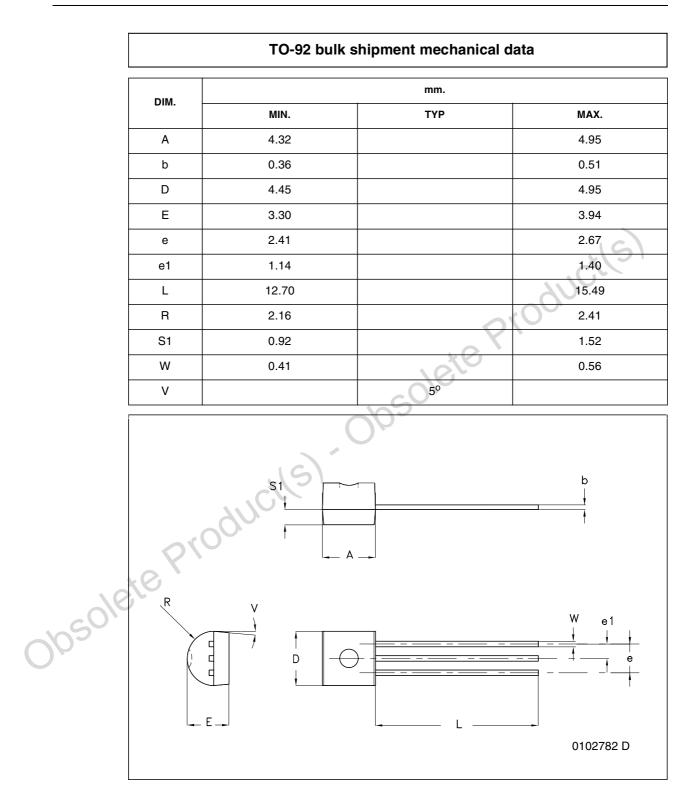


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

57

obsolete Product(s). Obsolete Product(s)





4 Revision history

Table 5.Document revision history

Date	Revision	Changes
08-Mar-2010	1	First release.
28-Apr-2010	2	Inserted V _F maximum value Table 4 on page 3.

obsolete Product(s). Obsolete Product(s)



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

Doc ID 17236 Rev 2

